This listing of claims will replace all prior versions, and listings, of claims in the application:

Claim 1 (canceled)

- 1 Claim 2 (currently amended): A solid-state image sensing
- 2 apparatus according to claim 1 comprising:
- an effective signal photoelectric conversion unit to
- 4 receive object light;
- 5 a light-shielded reference signal photoelectric
- 6 conversion unit to output an optical black level equivalent
- 7 signal; and
- 8 a noise suppressing circuit which suppresses a reset
- 9 variation for each pixel,
- wherein in addition to an output from the effective
- 11 signal photoelectric conversion unit, one of an output from
- 12 the reference signal photoelectric conversion unit and a
- 13 predetermined reference voltage is selectively output, and
- 14 wherein switching between the predetermined
- 15 reference voltage and the output from the reference signal
- 16 photoelectric conversion unit is done by changing a driving
- 17 signal of the noise suppressing circuit.
 - 1 Claim 3 (currently amended): A solid-state image sensing
 - 2 apparatus according to claim 12, wherein the predetermined
 - 3 reference voltage is a voltage to be applied to the reference
 - 4 signal photoelectric conversion unit.
 - 1 Claim 4 (currently amended): A solid-state image sensing
 - 2 apparatus according to claim +2, wherein the noise suppressing
 - 3 circuit includes a switch unit which switches at least between

- 4 the predetermined reference voltage and the output from the
- 5 reference signal photoelectric conversion unit, and
- in which whether an output signal from the reference
- 7 signal photoelectric conversion unit can be read out can and be
- 8 selected.

Claim 5 (canceled)

- 1 Claim 6 (currently amended): A solid-state image sensing
- 2 apparatus—according to claim 1 comprising:
- an effective signal photoelectric conversion unit to
- 4 receive object light;
- 5 <u>a light-shielded reference signal photoelectric</u>
- 6 conversion unit to output an optical black level equivalent
- 7 signal; and
- a noise suppressing circuit which suppresses a reset
- 9 variation for each pixel,
- 10. wherein in addition to an output from the effective
- 11 signal photoelectric conversion unit, one of an output from
- 12 the reference signal photoelectric conversion unit and a
- 13 predetermined reference voltage is selectively output,
- 14 wherein the noise suppressing circuit has at least a
- 15 clamp capacitor, a sample-and-hold switch, a clamp switch, and
- 16 a sample-and-hold capacitor, which are connected to each of
- 17 vertical signal lines extending from the effective signal
- 18 photoelectric conversion unit and the reference signal
- 19 photoelectric conversion unit, and
- in which one of the output from the reference signal
- 21 photoelectric conversion unit and the predetermined reference
- voltage is held in the sample-and-hold capacitor for the
- 23 reference signal photoelectric conversion unit and output by
- 24 driving and controlling the sample-and-hold switch and the

- 25 clamp switch of the vertical signal lines extending from the
- 26 reference signal photoelectric conversion unit.
 - 1 Claim 7 (currently amended): A solid-state image sensing
 - 2 apparatus according to claim 1 comprising:
 - an effective signal photoelectric conversion unit to
 - 4 receive object light;
 - 5 <u>a light-shielded reference signal photoelectric</u>
 - 6 conversion unit to output an optical black level equivalent
 - 7 signal; and
 - a noise suppressing circuit which suppresses a reset
 - 9 variation for each pixel,
- wherein in addition to an output from the effective
- 11 signal photoelectric conversion unit, one of an output from
- 12 the reference signal photoelectric conversion unit and a
- 13 predetermined reference voltage is selectively output,
- 14 _____wherein the noise suppressing circuit has at least a
- 15 reset signal capacitor, a reset signal switch, an optical
- 16 signal capacitor, and an optical signal switch, which are
- 17 connected to each of vertical signal lines extending from the
- 18 effective signal photoelectric conversion unit and the
- 19 reference signal photoelectric conversion unit, and
- in which in a predetermined case, both of the reset
- 21 signal capacitor and the optical signal capacitor are caused
- 22 to hold reset signal components and output the reset signal
- 23 components by driving and controlling the reset signal switch
- 24 and the optical signal switch.
 - 1 Claim 8 (original): A solid-state image sensing apparatus
 - 2 according to claim 7, wherein the predetermined case is a case
 - 3 in which an incident light amount of the object light is
- 4 large.

- 1 Claim 9 (currently amended): A solid-state image sensing
- 2 apparatus according to claim 1 comprising:
- an effective signal photoelectric conversion unit to
- 4 receive object light;
- a light-shielded reference signal photoelectric
- 6 conversion unit to output an optical black level equivalent
- 7 signal; and
- a noise suppressing circuit which suppresses a reset
- 9 variation for each pixel,
- wherein in addition to an output from the effective
- 11 signal photoelectric conversion unit, one of an output from
- 12 the reference signal photoelectric conversion unit and a
- 13 predetermined reference voltage is selectively output,
- 14 wherein the noise suppressing circuit has at least a
- 15 capacitor connected to each of vertical signal lines extending
- 16 from the effective signal photoelectric conversion unit and
- 17. the reference signal photoelectric conversion unit,
- a first power supply line which supplies a power to
- 19 the effective signal photoelectric conversion unit, and
- a second power supply line which supplies a power to
- 21 the reference signal photoelectric conversion unit, and
- in which in a predetermined case, a potential of a
- 23 vertical signal line extending from the reference signal
- 24 photoelectric conversion unit is fixed to GND by the second
- 25 power supply line, and the predetermined reference voltage is
- 26 held in the capacitor extending from the reference signal
- 27 photoelectric conversion unit and output.
 - 1 Claim 10 (original): A solid-state image sensing apparatus
 - 2 according to claim 9, wherein the predetermined case is a case

in which an incident light amount of the object light is 3 large. 4 1 Claim 11 (currently amended): A solid-state image sensing apparatus according to claim 1 comprising: 2 an effective signal photoelectric conversion unit to 3 receive object light; 4 a light-shielded reference signal photoelectric 5 6 conversion unit to output an optical black level equivalent signal; and 7 8 a noise suppressing circuit which suppresses a reset variation for each pixel, 9 wherein in addition to an output from the effective 10 signal photoelectric conversion unit, one of an output from 11 the reference signal photoelectric conversion unit and a 12 predetermined reference voltage is selectively output, 13 which further comprises an output amplifier which 14 15amplifies an output from the noise suppressing circuit, and in which a signal output level of the effective 16

signal photoelectric conversion unit is corrected selectively

on the basis of one of a pixel signal component of the

reference signal photoelectric conversion unit and a reset

level of the output amplifier, which is different from the

Claim 12 (canceled)

signal component.

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